CMOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

The RCA-CD4060A consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-0's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of $\phi_I(\phi_O)$. All inputs and outputs are fully buffered.

These types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic package (E suffix), 16-lead ceramic flat packages (K suffix), and in chip form (H suffix).

Features:

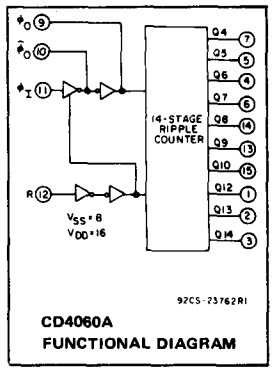
- **4-MHz operating frequency (typ.) at $V_{DD} - V_{SS}$ = 10 V**
- **Common reset**
- **Fully static operation**
- **10 buffered outputs available**
- **Quiescent current specified to 15 V**
- **Maximum input leakage current of 1 μA at 15 V (full package-temperature range)**
- **1-V noise margin (full package-temperature range)**

Oscillator Features:

- **All active components on chip**
- **RC or crystal oscillator configuration**

Applications:

- **Timers**
- **Frequency dividers**



CD4060A FUNCTIONAL DIAGRAM

MAXIMUM RATINGS, *Absolute-Maximum Values:*

STORAGE TEMPERATURE RANGE (T_{stg}) ..... −65 to +150°C
OPERATING-TEMPERATURE RANGE (T_A):
PACKAGE TYPES D, F, K, H ..... −55 to +125°C
PACKAGE TYPE E ..... −40 to +85°C
DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... −0.5 to +15 V
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = −40 to +60°C (PACKAGE TYPE E) ..... 500 mW
For T_A = +60 to +85°C (PACKAGE TYPE E) ..... Derate Linearly at 12 mW/°C to 200 mW
For T_A = −55 to +100°C (PACKAGE TYPES D, F, K) ..... 500 mW
For T_A = +100 to +125°C (PACKAGE TYPES D, F, K) ..... Derate Linearly at 12 mW/°C to 200 mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
For T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) ..... 100 mW
INPUT VOLTAGE RANGE, ALL INPUTS ..... −0.5 to V_{DD} +0.5 V
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 s max. ..... +265°C

RECOMMENDED OPERATING CONDITIONS at T_A = 25°C, Except as Noted.
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V_{DD} (V)	LIMITS				UNITS
		D, F, K, H Packages		*E Package*		
		Min.	Max.	Min.	Max.	
Supply-Voltage Range (For T_A = Full Package-Temperature Range)		3	12	3	12	V
Input-Pulse Width, t_W f = 100 kHz	5	400	–	500	–	ns
	10	110	–	125	–	
Input-Pulse Rise & Fall Time, $t_{r\phi}$, $t_{f\phi}$	5	–	15	–	15	μs
	10	–	7.5	–	7.5	
Input-Pulse Frequency, f_ϕ	5	–	1	–	0.9	MHz
	10	–	3	–	2.75	
Reset Pulse Width, t_W	5	1000	–	1250	–	ns
	10	500	–	600	–	

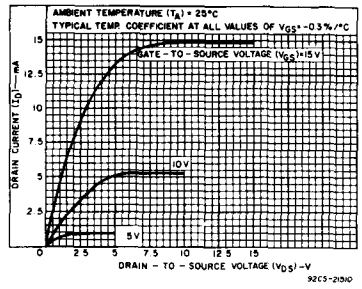


Fig. 1 – Typical n-channel drain characteristics.

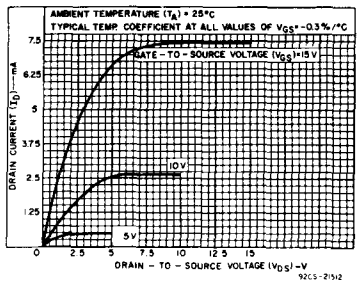


Fig. 2 – Minimum n-channel drain characteristics.

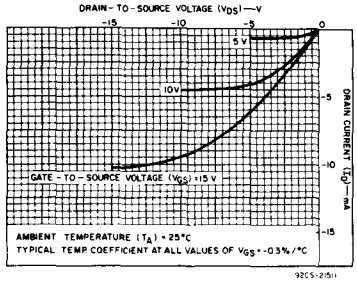


Fig. 3 – Typical p-channel drain characteristics.

CD4060A Types

STATIC ELECTRICAL CHARACTERISTICS

Characteristic	Conditions			Limits at Indicated Temperatures (°C)								Units
				D, F, K, H Packages				E Package				
	V_O (V)	V_{IN} (V)	V_{DD} (V)	−55	+25 Typ.	+25 Limit	+125	−40	+25 Typ.	+25 Limit	+85	
Quiescent Device Current I_L Max.	–	–	5	15	0.5	15	900	50	1	50	700	μA
	–	–	10	25	1	25	1500	100	2	100	1400	
	–	–	15	50	2.5	50	2000	500	5	500	5000	
Output Voltage: Low Level, V_{OL}	–	5	5	0 Typ.; 0.05 Max.								V
	–	10	10	0 Typ.; 0.05 Max.								
High Level V_{OH}	–	0	5	4.95 Min.; 5 Typ.								
	–	0	10	9.95 Min.; 10 Typ.								
Noise Immunity: Inputs Low, V_{NL}	4.2	–	5	1.5 Min.; 2.25 Typ.								V
	9	–	10	3 Min.; 4.5 Typ.								
Inputs High V_{NH}	0.8	–	5	1.5 Min.; 2.25 Typ.								
	10	–	10	3 Min.; 4.5 Typ.								
Noise Margin: Inputs Low, V_{NML}	4.5	–	5	1 Min.								V
	9	–	10	1 Min.								
Inputs High, V_{NMH}	0.5	–	5	1 Min.								
	1	–	10	1 Min.								
Output Drive Current:* n-Channel (Sink), I_DN Min.	0.5	–	5	0.22	0.36	0.18	0.125	0.21	0.36	0.18	0.15	mA
	0.5	–	10	0.44	0.75	0.36	0.25	0.42	0.75	0.36	0.3	
p-Channel (Source), I_DP Min.	4.5	–	5	-0.15	-0.25	-0.125	-0.085	-0.145	-0.25	-0.125	-0.1	
	9.5	–	10	-0.3	-0.5	-0.25	-0.175	-0.29	-0.5	-0.25	-0.2	
Input Leakage Current, I_{IL}, I_{IH}	Any Input	–	15	$\pm 10^{-5}$ Typ., ±1 Max.								μA

* Data not applicable to Terminal 9 or 10

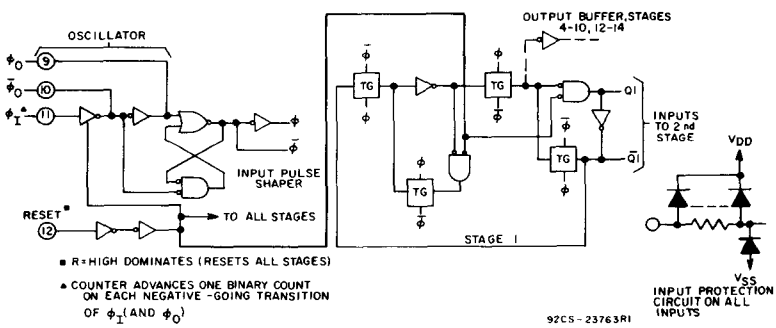


Fig. 7 – Logic diagram of CD4060A oscillator, pulse shaper, and 1 of 14 counter stages.

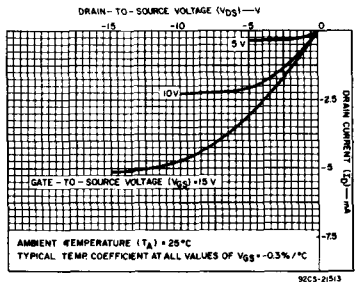


Fig. 4 – Minimum p-channel drain characteristics.

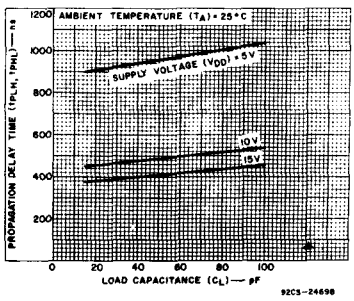


Fig. 5 – Typical propagation delay time vs. load capacitance (ϕ_I to Q4 output).

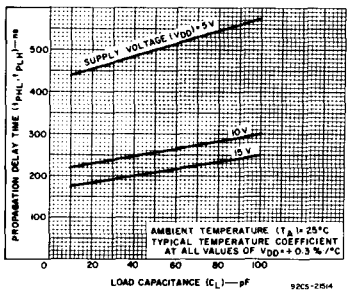


Fig. 6 – Typical propagation delay time vs. load capacitance (Q_n to Q_{n+1}).

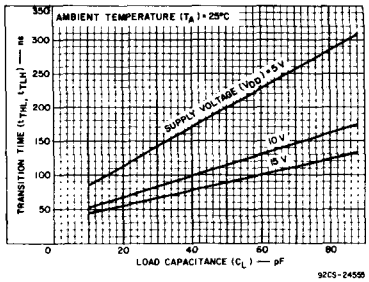


Fig. 8 – Typical output transition time vs. load capacitance.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r, t_f = 20 ns, C_L = 15 pF, R_L = 200 kΩ

CHARACTERISTIC	TEST CONDITIONS	V_{DD} (V)	LIMITS D, F, K, H Packages Min.	Typ.	Max.	LIMITS E Package Min.	Typ.	Max.	UNITS
Input-Pulse Operation									
Propagation Delay Time, ϕ_I to Q4 Out; t_{PHL}, t_{PLH}		5	–	900	1800	–	900	1900	ns
		10	–	450	900	–	450	950	
Propagation Delay Time, Q_n to Q_{n+1}; t_{PHL}, t_{PLH}		5	–	450	900	–	450	950	ns
		10	–	225	450	–	225	475	
Transition Time, t_{THL}, t_{TLH}		5	–	150	300	–	150	350	ns
		10	–	75	150	–	75	175	
Min. Input-Pulse Width t_W	f=100 kHz	5	–	200	400	–	200	500	ns
		10	–	75	110	–	75	125	
Input-Pulse Rise & Fall Time, $t_{r\phi}$, $t_{f\phi}$		5	–	–	15	–	–	15	μs
		10	–	–	7.5	–	–	7.5	
Max. Input-Pulse Frequency, f_ϕ		5	1	1.75	–	0.9	1.75	–	MHz
		10	3	4	–	2.75	4	–	
Input Capacitance, C_I	Any Input		–	5	–	–	5	–	pF
Reset Operation									
Propagation Delay Time, t_{PHL}		5	–	500	1000	–	500	1250	ns
		10	–	250	500	–	250	600	
Minimum Reset Pulse Width, t_W		5	–	500	1000	–	500	1250	ns
		10	–	250	500	–	250	600	

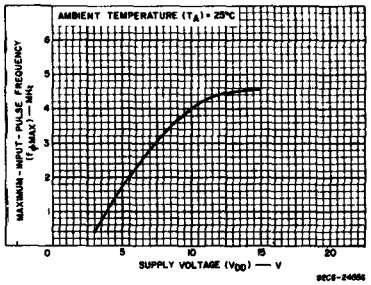


Fig. 9 – Typical maximum-input-pulse frequency vs. supply voltage.

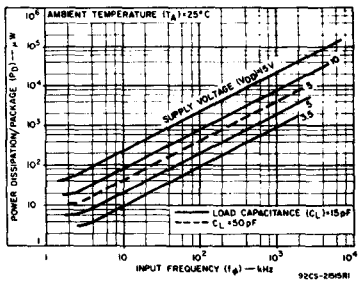


Fig. 10 – Typical dynamic power dissipation characteristics.

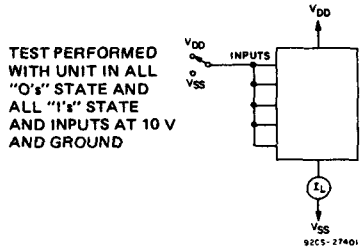


Fig. 11 – Quiescent-device current test circuit.

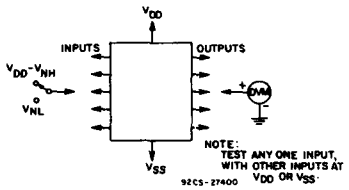


Fig. 12 – Noise-immunity test circuit.

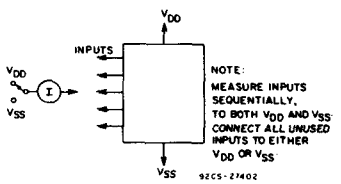


Fig. 13 – Input-leakage-current test circuit.